MMBTA56LT1 is a Preferred Device

## **Driver Transistors**

### **PNP Silicon**

#### **Features**

• Pb-Free Packages are Available

### **MAXIMUM RATINGS**

| Rating                       |                    | Symbol           | Value      | Unit |
|------------------------------|--------------------|------------------|------------|------|
| Collector – Emitter Voltage  | MMBTA55<br>MMBTA56 | V <sub>CEO</sub> | -60<br>-80 | Vdc  |
| Collector - Base Voltage     | MMBTA55<br>MMBTA56 | V <sub>CBO</sub> | -60<br>-80 | Vdc  |
| Emitter – Base Voltage       |                    | $V_{EBO}$        | -4.0       | Vdc  |
| Collector Current - Continuo | us                 | I <sub>C</sub>   | -500       | mAdc |

### THERMAL CHARACTERISTICS

| Characteristic   | Symbol                            | Max         | Unit        |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board<br>(Note 1) T <sub>A</sub> = 25°C<br>Derate above 25°C         | P <sub>D</sub>                    | 225<br>1.8  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient  | $R_{\theta JA}$                   | 556         | °C/W        |
| Total Device Dissipation Alumina<br>Substrate, (Note 2) T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 300<br>2.4  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient  | $R_{\theta JA}$                   | 417         | °C/W        |
| Junction and Storage Temperature   | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

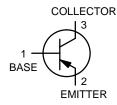
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



### ON Semiconductor®

### http://onsemi.com





SOT-23 **CASE 318** STYLE 6

#### **MARKING DIAGRAM**



2xx = Device Code

x = H for MMBTA55LT1

xx = GM for MMBTA56LT1

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

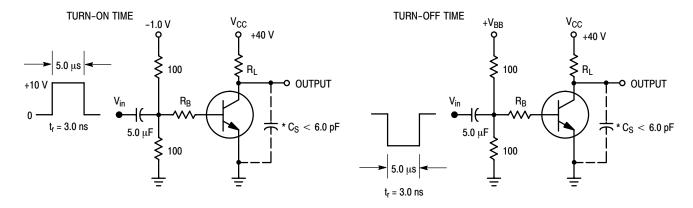
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic  | Symbol             | Min                  | Max        | Unit         |      |
|---|--------------------|----------------------|------------|--------------|------|
| OFF CHARACTERISTICS   |                    |                      |            |              |      |
| Collector – Emitter Breakdown Voltage (Note 3) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$   | MMBTA55<br>MMBTA56 | V <sub>(BR)CEO</sub> | -60<br>-80 | -<br>-       | Vdc  |
| Emitter – Base Breakdown Voltage $(I_E = -100 \mu Adc, I_C = 0)$  |                    | V <sub>(BR)EBO</sub> | -4.0       | -            | Vdc  |
| Collector Cutoff Current (V <sub>CE</sub> = -60 Vdc, I <sub>B</sub> = 0)  |                    | I <sub>CES</sub>     | -          | -0.1         | μAdc |
| Collector Cutoff Current<br>$(V_{CB} = -60 \text{ Vdc}, I_{E} = 0)$<br>$(V_{CB} = -80 \text{ Vdc}, I_{E} = 0)$  | MMBTA55<br>MMBTA56 | I <sub>CBO</sub>     | -<br>-     | -0.1<br>-0.1 | μAdc |
| ON CHARACTERISTICS  |                    |                      |            |              |      |
| DC Current Gain $ \begin{aligned} &(I_C = -10 \text{ mAdc},  V_{CE} = -1.0 \text{ Vdc}) \\ &(I_C = -100 \text{ mAdc},  V_{CE} = -1.0 \text{ Vdc}) \end{aligned} $ |                    | h <sub>FE</sub>      | 100<br>100 | -<br>-       | -    |
| Collector – Emitter Saturation Voltage $(I_C = -100 \text{ mAdc}, I_B = -10 \text{ mAdc})$  |                    | V <sub>CE(sat)</sub> | -          | -0.25        | Vdc  |
| Base-Emitter On Voltage ( $I_C = -100 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}$ )  |                    | V <sub>BE(on)</sub>  | -          | -1.2         | Vdc  |
| SMALL-SIGNAL CHARACTERISTICS  |                    |                      |            |              |      |
| Current – Gain – Bandwidth Product (Note 4)<br>(I <sub>C</sub> = –100 mAdc, V <sub>CE</sub> = –1.0 Vdc, f = 100 MHz)  |                    | f⊤                   | 50         | _            | MHz  |

<sup>3.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.



\*Total Shunt Capacitance of Test Jig and Connectors For PNP Test Circuits, Reverse All Voltage Polarities

**Figure 1. Switching Time Test Circuits** 

<sup>4.</sup> f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.

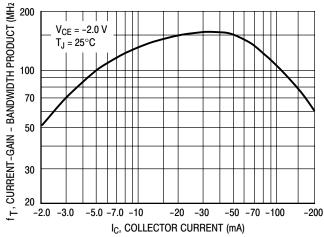


Figure 2. Current-Gain — Bandwidth Product

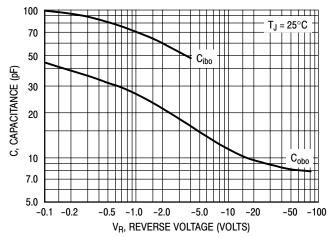


Figure 3. Capacitance

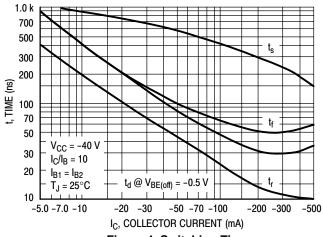


Figure 4. Switching Time

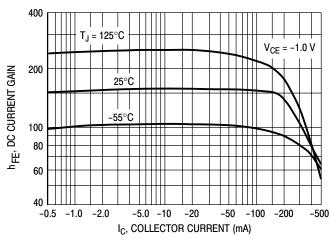


Figure 5. DC Current Gain

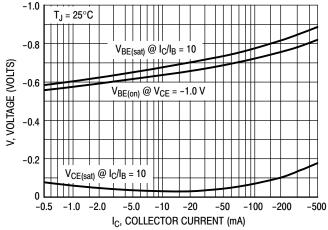
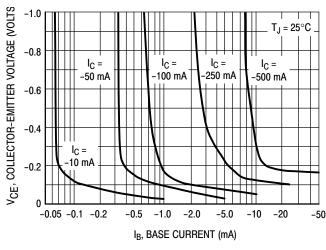


Figure 6. "ON" Voltages



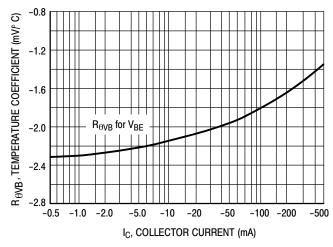


Figure 7. Collector Saturation Region

Figure 8. Base-Emitter Temperature Coefficient

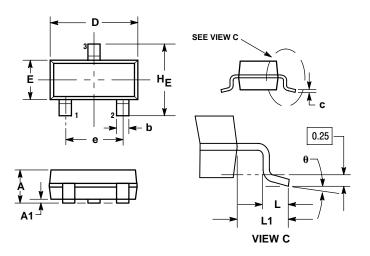
### **ORDERING INFORMATION**

| Device Order Number | Package Type        | Shipping <sup>†</sup><br>3,000 / Tape & Reel |  |  |
|---------------------|---------------------|--|--|--|
| MMBTA55LT1          | SOT-23              |  |  |  |
| MMBTA55LT1G         | SOT-23<br>(Pb-Free) | 3,000 / Tape & Reel                          |  |  |
| MMBTA55LT3          | SOT-23              | 10,000 / Tape & Reel                         |  |  |
| MMBTA55LT3G         | SOT-23<br>(Pb-Free) | 10,000 / Tape & Reel                         |  |  |
| MMBTA56LT1          | SOT-23              | 3,000 / Tape & Reel                          |  |  |
| MMBTA56LT1G         | SOT-23<br>(Pb-Free) | 3,000 / Tape & Reel                          |  |  |
| MMBTA56LT3          | SOT-23              | 10,000 / Tape & Reel                         |  |  |
| MMBTA56LT3G         | SOT-23<br>(Pb-Free) | 10,000 / Tape & Reel                         |  |  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 



#### NOTES

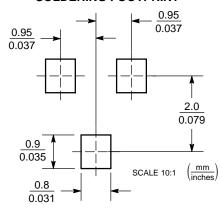
- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

|     | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| Α   | 0.89        | 1.00 | 1.11 | 0.035  | 0.040 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015  | 0.018 | 0.020 |
| С   | 0.09        | 0.13 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| е   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.081 |
| L   | 0.10        | 0.20 | 0.30 | 0.004  | 0.008 | 0.012 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.029 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |

#### STYLE 6:

- PIN 1. BASE 2. EMITTER
  - COLLECTOR

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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